IA30N4452 PA module

440-520M,30W, 12.5V, 2 stage for Mobile radio

Description

IA30N4452 is a rugged 30W RF LDMOS Amplifier Module for 12.5V mobile radios that operate in the 440 to 520MHz range. The battery can be connected directly to the drain of the modules

This module is designed for non-linear modulation, but may also be used for linear modulation by

setting the drain quiescent current with the gate voltage and controlling the output power with the input power



Features

- Rugged LDMOS technology
- Pout>30W, Eff>50% @ Vds=12.5V, Vgs=5.2V, Pin=50mW
- Broadband Frequency Range: 440-520MHz
- · Metal shielding structure
- Module Size: 67 x 19.4 x 9.9 mm
- DC block capacitor integrated
- · Linear and non linear operation supported

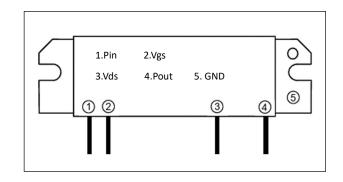


Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DrainSource Voltage	V _{DSS}	+65	Vdc
GateSource Voltage	V _{GS}	-10 to +10	Vdc
Operating Voltage	V _{DD}	+24	Vdc
Storage Temperature Range	Tstg	-65 to +150	°C
Case Operating Temperature	Tc	+150	°C
Operating Junction Temperature	TJ	+225	°C

Table 2. ELECTRICAL CHARACTERISTICS (Tcase=+25°C, ZG=ZL=50ohm , unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
f	Frequency Range	E 1	440	-	520	MHz
Pout	Output Power		30	2	<u>u</u>	W
Т	Total Efficiency		50	2	-	%
2fo	2 _{nd} Harmonic	Vpp=12.5V, Vgg=5V, Pin=50mW	-	-	-40	dBc
3fo	3rd Harmonic		-	-	-60	dBc
in	Input VSWR		1	-	4:1	-
loo	Leakage Current	VDD=17V, VGG=0V, Pin=0W	-	-	3	mA
-	Load VSWR Tolerance	V _{DD} =15.2V, P _{in} =50mW, P _{out} =30W (V _{GG} adj.), Load VSWR=20:1(All phase)	No degradation or destroy		-	
-	Stability	V _{DD} =10/12.5/15.2V, P _{in} =25/50/70mW, P _{out} ≦ 40W (V _{GG} control), Load VSWR=3:1(All phase)	No parasitic oscillation more than -60dBc		-	

Figure 1: Network analyzer Output S11/S21

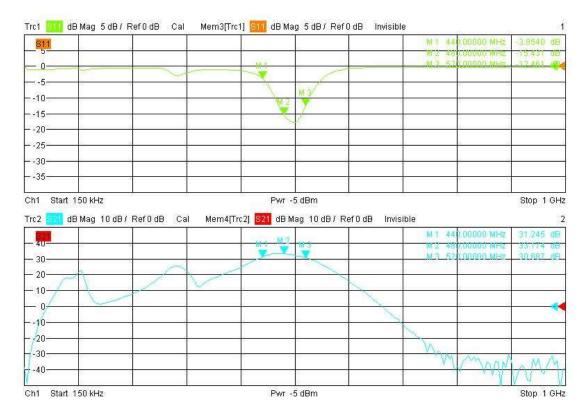
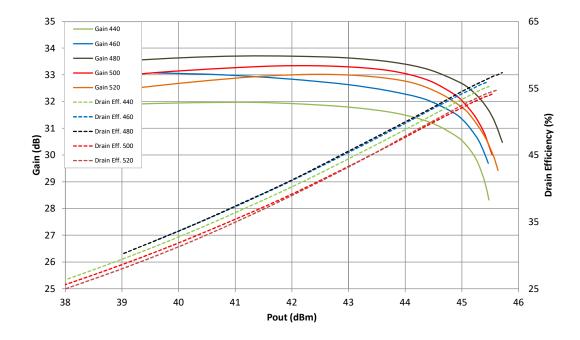
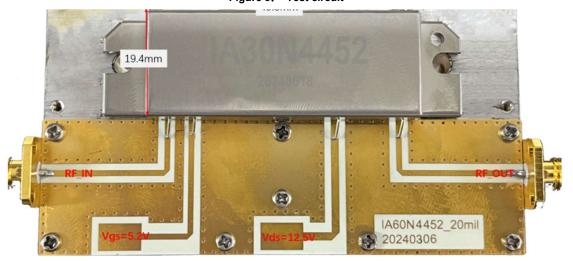


Figure 2: CW Power gain, Efficiency as function of output Power



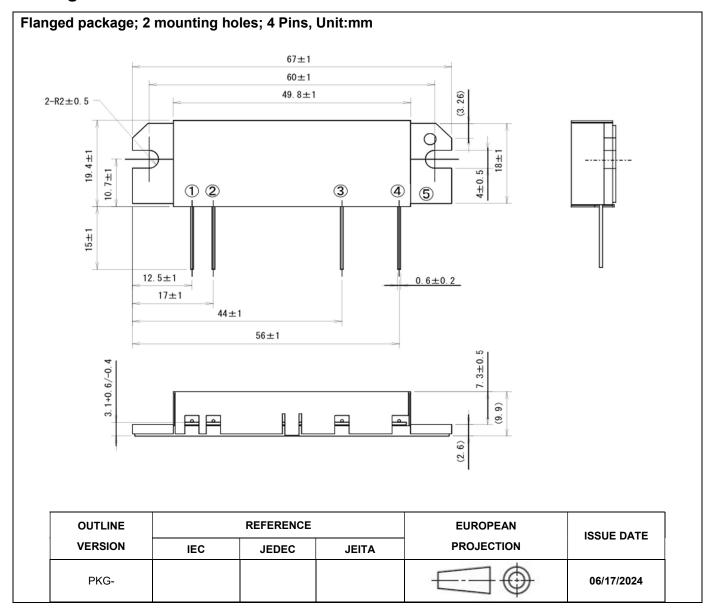
V _{DS} = 12.5V, V _{gs} = 5.2V, I _{dq} =560mA					
Freq (MHz)	P1(dBm)	P1 Gain (dB)	P3dB(dBm)	P3dB(W)	EFF (%)
440	44.65	31.0	45.40	34.7	55.0
450	44.23	31.5	45.24	33.4	54.7
460	44.34	32.1	45.39	34.6	55.7
470	44.65	32.5	45.57	36.1	56.8
480	44.95	32.7	45.67	36.9	57.2
490	44.99	32.7	45.63	36.6	56.4
500	44.79	32.4	45.48	35.3	53.9
510	44.73	32.3	45.43	34.9	53.6
520	44.81	32.0	45.54	35.8	54.5

Figure 3: Test circuit



IA30N4452 PA module

Package Outline



Document Number: IA30N4452 Product Datasheet V1.0

Revision history

Table 5. Document revision history

Date	Revision	Datasheet Status
2024/6/17	Rev 1.0	Product Datasheet Creation

Application data based on HL-24-10

Disclaimers

Specifications are subject to change without notice. Innogration believes the information contained within this data sheet to be accurate and reliable. However, no responsibility is assumed by Innogration for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Innogration . Innogration makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose. "Typical" parameters are the average values expected by Innogration in large quantities and are provided for information purposes only. These values can and do vary in different applications and actual performance can vary over time. All operating parameters should be validated by customer's technical experts for each application. Innogration products are not designed, intended or authorized for use as components in applications intended for surgical implant into the body or to support or sustain life, in applications in which the failure of the Innogration product could result in personal injury or death or in applications for planning, construction, maintenance or direct operation of a nuclear facility. For any concerns or questions related to terms or conditions, pls check with Innogration and authorized distributors

Copyright © by Innogration (Suzhou) Co.,Ltd.